



3 GHz SMA LATCHING S.P.9 T. SWITCH

OPTIONS : INDICATOR /SELF CUT-OFF /AUTO RESET / TTL DRIVE /SUPP.DIODES

R F CHARACTERISTICS

NUMBER OF WAYS : 9
 FREQUENCY RANGE : 0 - 3 GHz
 IMPEDANCE : 50 Ohms

FREQUENCY (GHz)	0 - 3
V.S.W.R <=	1.20
INSERT. LOSS <=	0.20 dB
ISOLATION >=	80 dB
AVER. POWER (*)	240 W

ELECTRICAL CHARACTERISTICS

ACTUATOR : LATCHING
 NOMINAL CURRENT AT 25° C (±10%) : 1280 mA
 ACTUATOR VOLTAGE (Vcc) : 12V (10.2 to 13V) / NEGATIVE COMMON
 TERMINALS : 25 pins D-SUB male connector
 INDICATOR RATING : 1 W / 30 V / 100 mA
 SELF CUT-OFF TIME : 40 ms < CT < 120 ms
 TTL INPUTS (E) - High level : 2.2 to 5.5V / 800µA at 5V
 - Low level : 0 to 0.8V / 20µA at 0.8V

MECHANICAL CHARACTERISTICS

CONNECTORS : SMA female per MIL-C 39012
 LIFE : 2.000.000 cycles per position
 SWITCHING TIME (nominal voltage;25° C) : < 50 ms
 CONSTRUCTION : splashproof
 WEIGHT : < 360 g

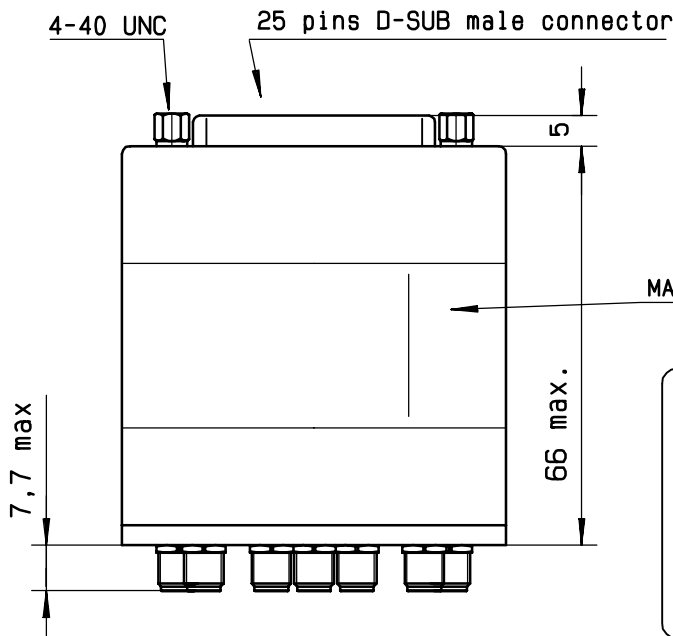
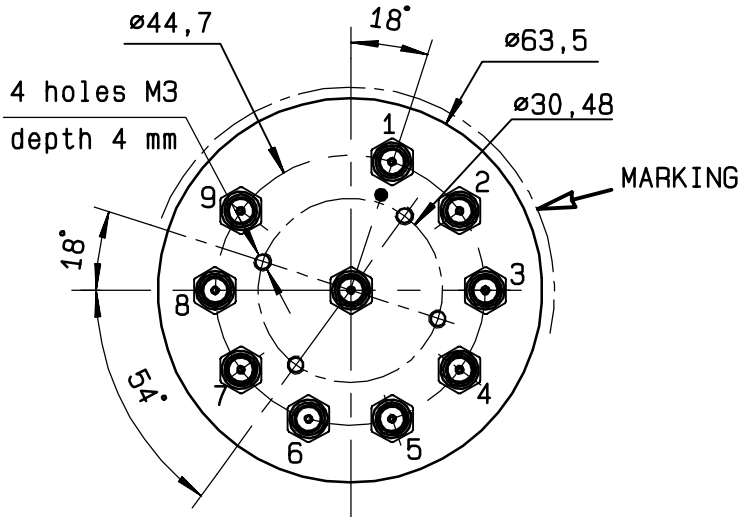
ENVIRONMENTAL CHARACTERISTICS

OPERATING TEMPERATURE RANGE (°C) : -40 , +85
 STORAGE TEMPERATURE RANGE (°C) : -55 , +85

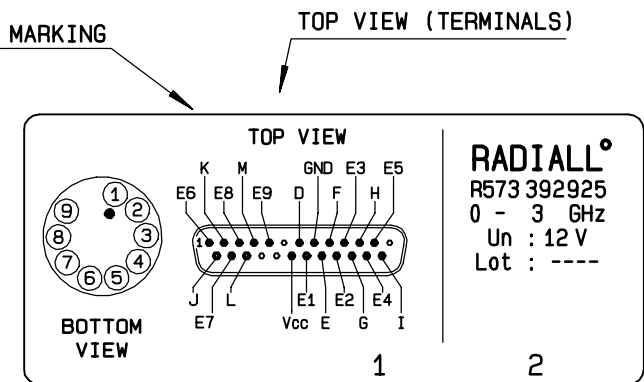
(* : average power at 25° C per RF path)

This information is given as an indication. In the continual goal to improve our products, we reserve the right to make any modifications judged necessary

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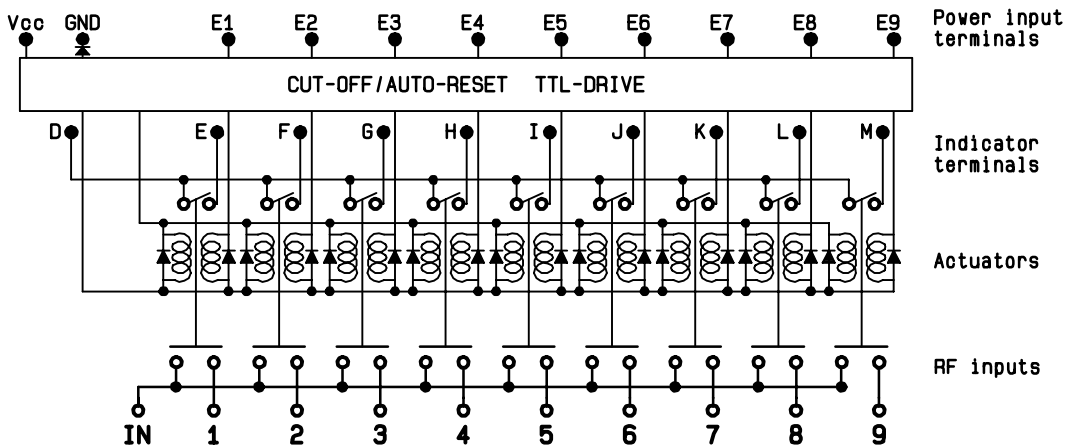


TTL input	RF continuity	Ind.
E1 = 1	IN ↔ 1	D.E
E2 = 1	IN ↔ 2	D.F
E3 = 1	IN ↔ 3	D.G
E4 = 1	IN ↔ 4	D.H
E5 = 1	IN ↔ 5	D.I
E6 = 1	IN ↔ 6	D.J
E7 = 1	IN ↔ 7	D.K
E8 = 1	IN ↔ 8	D.L
E9 = 1	IN ↔ 9	D.M



RADIALL^o
 R573 392925
 0 - 3 GHz
 Un : 12 V
 Lot : ----

SCHEMATIC DIAGRAM



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